International Rectifier

HFA08TB120SPbF

Ultrafast, Soft Recovery Diode

HEXFRED™

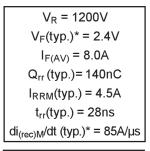
Features

- Ultrafast Recovery
- · Ultrasoft Recovery
- Very Low I_{RRM}
- · Very Low Q_{rr}
- · Specified at Operating Conditions
- Lead-Free

Benefits

- · Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- · Higher Frequency Operation
- · Reduced Snubbing
- · Reduced Parts Count

Base Cathode 2 2 1 3 N/C Anode





Description

International Rectifier's HFA08TB120S is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 volts and 8 amps continuous current, the HFA08TB120S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TB120S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

Absolute Maximum Ratings

	Parameter	Max.	Units
V _R	Cathode-to-Anode Voltage	1200	V
I _F @ T _C = 100°C	Continuous Forward Current	8.0	
I _{FSM}	Single Pulse Forward Current	130	Α
I _{FRM}	Maximum Repetitive Forward Current	32	1
P _D @ T _C = 25°C	Maximum Power Dissipation	73.5	w
P _D @ T _C = 100°C	Maximum Power Dissipation	29] vv
TJ	Operating Junction and	FF to 14F0	°C
T _{STG}	Storage Temperature Range	-55 to +150	

^{* 125°}C

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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
V_{BR}	Cathode Anode Breakdown Voltage	1200			٧	I _R = 100μA	
V _{FM}	Max Forward Voltage		2.6	3.3		I _F = 8.0A	
			3.4	4.3	V	I _F = 16A	
			2.4	3.1		I _F = 8.0A, T _J = 125°C	
I _{RM}	Max Reverse Leakage Current		0.31	10	μA	V _R = V _R Rated	
			135	1000	μΛ	$T_J = 125$ °C, $V_R = 0.8 \times V_R$ Rated	
C _T	Junction Capacitance		11	20	рF	V _R = 200V	
Ls	Series Inductance		8.0		- nH	Measured lead to lead 5mm from	
	Series inductance					package body	

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

-	-			-		-	•
	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
t _{rr}	Reverse Recovery Time		28			$I_F = 1.0A$, $di_f/dt = 200A/\mu s$, $V_R = 30V$	
t _{rr1}	See Fig. 5		63	95	ns	T _J = 25°C	
t _{rr2}			106	160		T _J = 125°C	I _F = 8.0A
I _{RRM1}	Peak Recovery Current		4.5	8.0	Α	T _J = 25°C	
I _{RRM2}	See Fig. 6		6.2	11	1 ^	T _J = 125°C	V _R = 200V
Q _{rr1}	Reverse Recovery Charge		140	380	nC	T _J = 25°C	
Q _{rr2}	See Fig. 7		335	880	1110	T _J = 125°C	di _f /dt = 200A/µs
di _{(rec)M} /dt1	Peak Rate of Fall of Recovery Current		133		A/us	T _J = 25°C	
di _{(rec)M} /dt2	During t _b See Fig. 8		85		- Α, μο	T _J = 125°C	

Thermal - Mechanical Characteristics

	Parameter	Min.	Тур.	Max.	Units
T _{lead} ①	Lead Temperature			300	°C
R _{thJC}	Thermal Resistance, Junction to Case			1.7	kW
R _{thJA} ②	Thermal Resistance, Junction to Ambient			40	NVV
Wt	Weight		2.0		g
			0.07		(oz)

① 0.063 in. from Case (1.6mm) for 10 sec

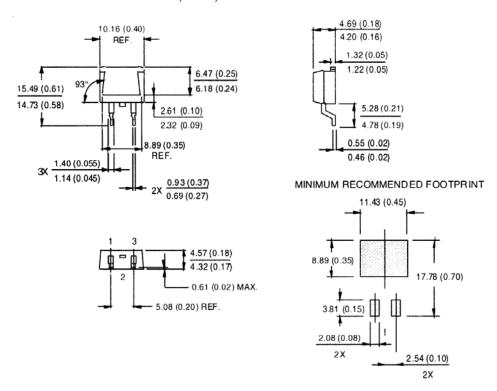
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② Typical Socket Mount



D²PAK Package Outline

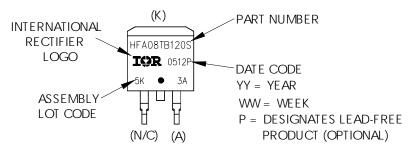
Dimensions are shown in millimeters (inches)



Conforms to JEDEC Outline D²PAK Dimensions in millimeters and inches

D²PAK Part Marking Information

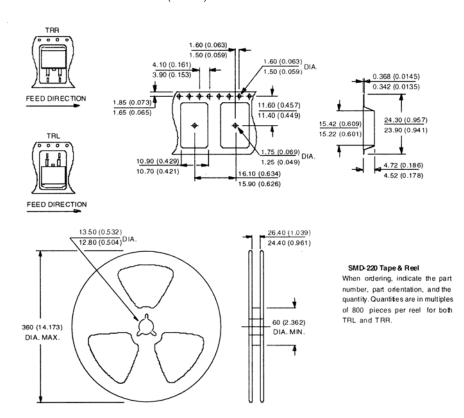
EXAMPLE: THIS IS A HFA08TB120S



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D²PAK Tape & Reel Information

Dimensions are shown in millimeters (inches)



Data and specifications subject to change without notice. This product has been designed and qualified for the Consumer market.

Qualifications Standards can be found on IR's Web site.



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